

### Features

- Center amplifying gate
- Metal case with ceramic insulator
- Low on-state and switching losses

### Typical Applications

- AC controllers
- DC and AC motor control
- Controlled rectifiers

$I_{T(AV)}$  1640A  
 $V_{DRM}/V_{RRM}$  3100~4200V  
 $I_{TSM}$  20 kA  
 $I^2t$  2000  $10^3 A^2S$



| SYMBOL                               | CHARACTERISTIC                                                       | TEST CONDITIONS                                                                                                             |                      | T <sub>J</sub> (°C) | VALUE |      |        | UNIT                             |
|--------------------------------------|----------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------|----------------------|---------------------|-------|------|--------|----------------------------------|
|                                      |                                                                      |                                                                                                                             |                      |                     | Min   | Type | Max    |                                  |
| I <sub>T(AV)</sub>                   | Mean on-state current                                                | 180° half sine wave 50Hz<br>Double side cooled,                                                                             | T <sub>C</sub> =55°C | 125                 |       |      | 1910   | A                                |
|                                      |                                                                      |                                                                                                                             | T <sub>C</sub> =70°C |                     |       |      | 1640   |                                  |
| V <sub>DRM</sub><br>V <sub>RRM</sub> | Repetitive peak off-state voltage<br>Repetitive peak reverse voltage | V <sub>DRM</sub> &V <sub>RRM</sub> tp=10ms<br>V <sub>DSM</sub> &V <sub>RSM</sub> = V <sub>DRM</sub> &V <sub>RRM</sub> +100V |                      | 125                 | 3100  |      | 4200   | V                                |
| I <sub>DRM</sub><br>I <sub>RRM</sub> | Repetitive peak current                                              | V <sub>DM</sub> = V <sub>DRM</sub><br>V <sub>RM</sub> = V <sub>RRM</sub>                                                    |                      | 125                 |       |      | 120    | mA                               |
| I <sub>TSM</sub>                     | Surge on-state current                                               | 10ms half sine wave                                                                                                         |                      | 125                 |       |      | 20     | kA                               |
| I <sup>2</sup> t                     | I <sup>2</sup> T for fusing coordination                             | V <sub>R</sub> =0.6V <sub>RRM</sub>                                                                                         |                      |                     |       |      | 2000   | A <sup>2</sup> s*10 <sup>3</sup> |
| V <sub>TO</sub>                      | Threshold voltage                                                    |                                                                                                                             |                      | 125                 |       |      | 1.17   | V                                |
| r <sub>T</sub>                       | On-state slop resistance                                             |                                                                                                                             |                      |                     |       |      | 0.35   | mΩ                               |
| V <sub>TM</sub>                      | Peak on-state voltage                                                | I <sub>TM</sub> =3220A, F=32kN                                                                                              |                      | 125                 |       |      | 2.30   | V                                |
| dv/dt                                | Critical rate of rise of off-state voltage                           | V <sub>DM</sub> =0.67V <sub>DRM</sub>                                                                                       |                      | 125                 |       |      | 1000   | V/μs                             |
| di/dt                                | Critical rate of rise of on-state current                            | V <sub>DM</sub> = 67%V <sub>DRM</sub><br>to 2000A, Gate source 1.5A<br>t <sub>r</sub> ≤0.5μs                                |                      | 125                 |       |      | 200    | A/μs                             |
| Q <sub>rr</sub>                      | Recovery charge                                                      | I <sub>TM</sub> =2000A,tp=2000μs, di/dt=-20A/μs,<br>V <sub>R</sub> =50V                                                     |                      | 125                 |       | 2000 |        | μC                               |
| I <sub>GT</sub>                      | Gate trigger current                                                 | V <sub>A</sub> =12V, I <sub>A</sub> =1A                                                                                     |                      | 25                  | 40    |      | 300    | mA                               |
| V <sub>GT</sub>                      | Gate trigger voltage                                                 |                                                                                                                             |                      |                     | 0.8   |      | 3.0    | V                                |
| I <sub>H</sub>                       | Holding current                                                      |                                                                                                                             |                      |                     | 20    |      | 300    | mA                               |
| V <sub>GD</sub>                      | Non-trigger gate voltage                                             | V <sub>DM</sub> =67%V <sub>DRM</sub>                                                                                        |                      | 125                 | 0.3   |      |        | V                                |
| R <sub>th(j-c)</sub>                 | Thermal resistance<br>Junction to case                               | At 180° sine double side cooled<br>Clamping force 32kN                                                                      |                      |                     |       |      | 0.013  | °C /W                            |
| R <sub>th(c-h)</sub>                 | Thermal resistance<br>case to heatsink                               |                                                                                                                             |                      |                     |       |      | 0.0035 |                                  |
| F <sub>m</sub>                       | Mounting force                                                       |                                                                                                                             |                      |                     | 27    |      | 34     | kN                               |
| T <sub>stg</sub>                     | Stored temperature                                                   |                                                                                                                             |                      |                     | -40   |      | 140    | °C                               |
| W <sub>t</sub>                       | Weight                                                               |                                                                                                                             |                      |                     |       | 820  |        | g                                |
| Outline                              | KT60cT65                                                             |                                                                                                                             |                      |                     |       |      |        |                                  |

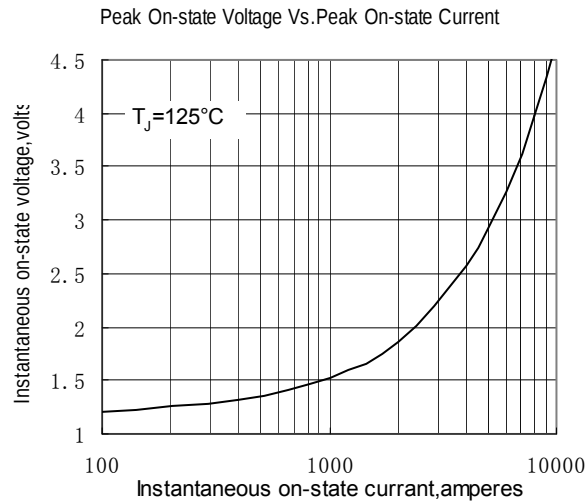


Fig.1

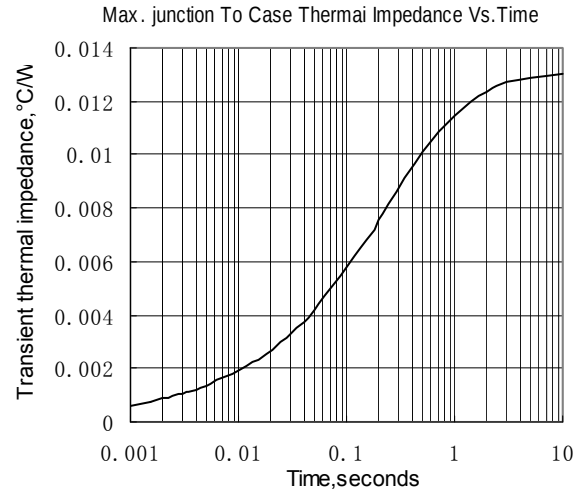


Fig.2

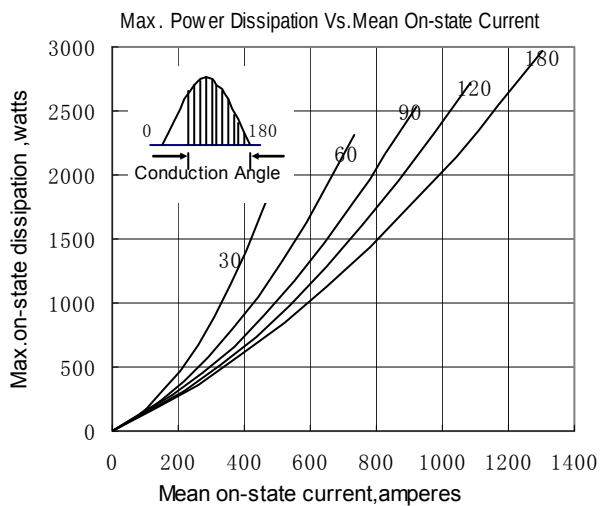


Fig.3

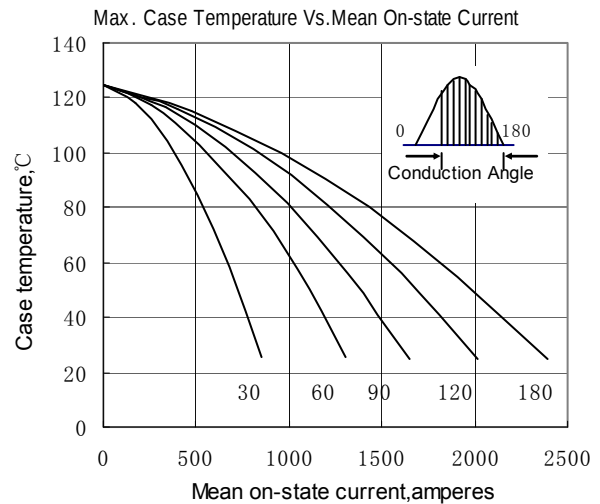
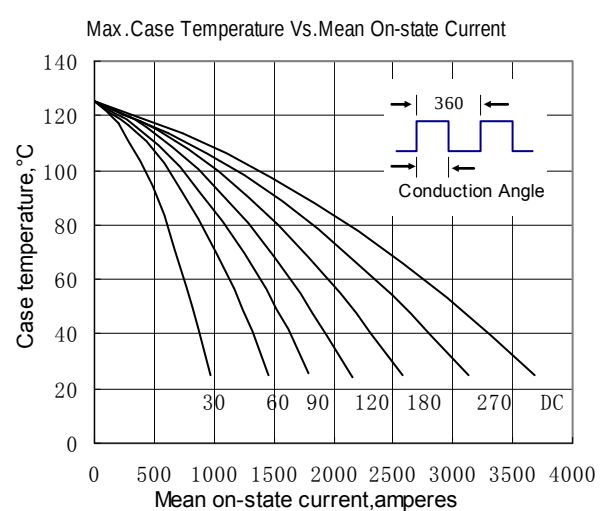
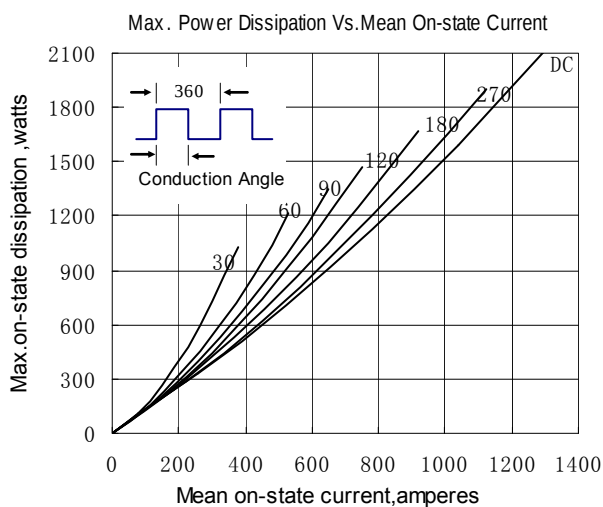


Fig.4



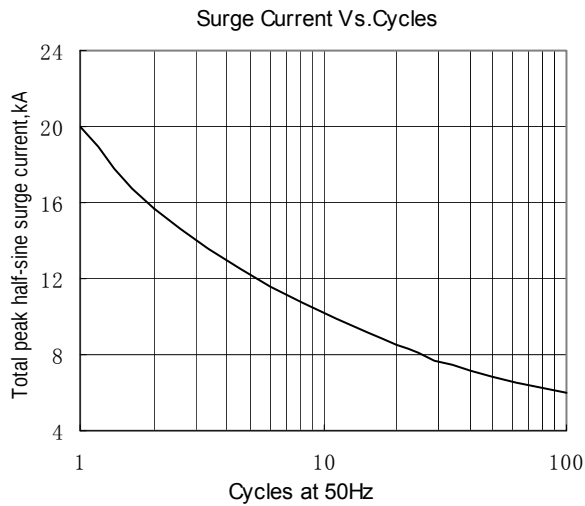


Fig.7

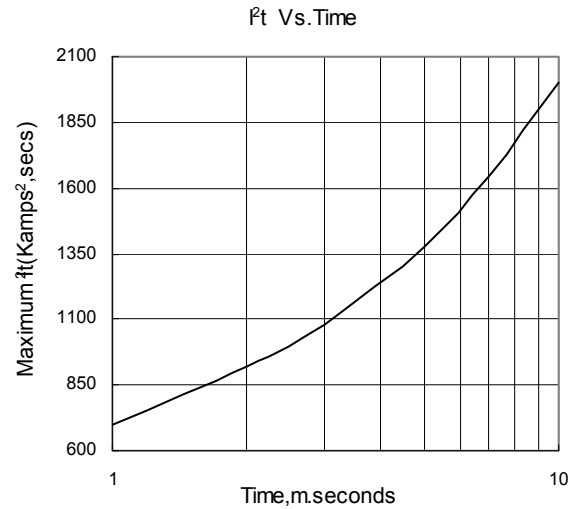


Fig.8

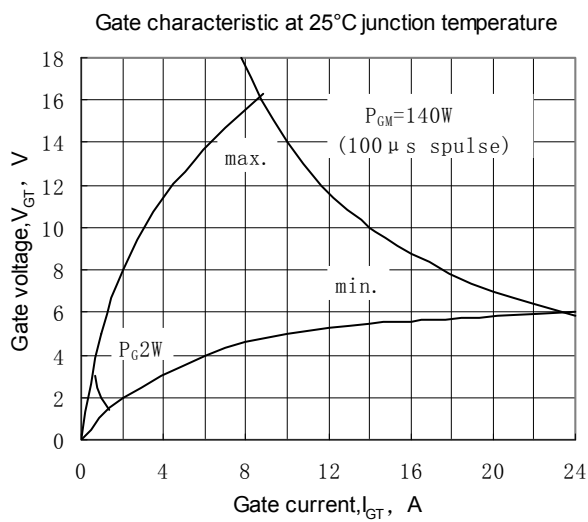


Fig.9

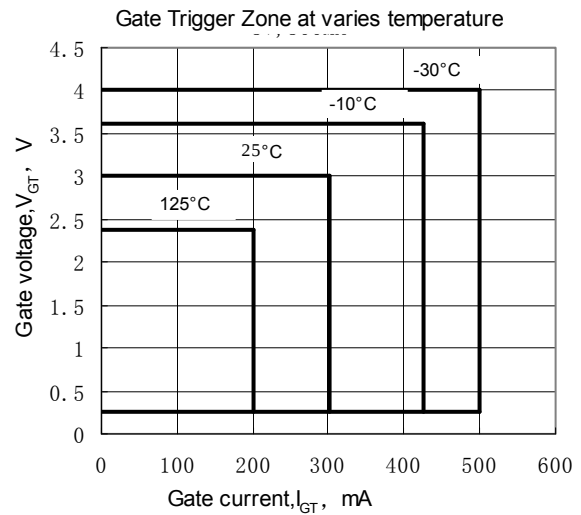


Fig.10

## Outline:

